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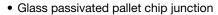
### **Surface Mount Ultrafast Plastic Rectifier**



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	3.0 A				
V <sub>RRM</sub> 100 V, 150 V, 200					
t <sub>rr</sub>	25 ns				
V <sub>F</sub> at I <sub>F</sub>	0.90 V				
T <sub>J</sub> max.	175 °C				
Package	DO-214AB (SMC)				
Diode variations	Single die				

#### **FEATURES**







• Low forward voltage, low power loss

High forward surge capability

• Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

AEC-Q101 qualified

• Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both, industrial and automotive.

#### **MECHANICAL DATA**

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, industrial grade Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B, ....)

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	$V_{RMM}$	100	150	200		
Maximum RMS voltage	$V_{RMS}$	70	105	140	V	
Maximum DC blocking voltage	$V_{DC}$	100	150	200		
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	3.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	125			А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175			°C	

# ESH3B, ESH3C, ESH3D

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage	I <sub>F</sub> = 3 A		V <sub>F</sub> <sup>(1)</sup>	0.90	V	
Maximum DC reverse current		T <sub>A</sub> = 25 °C	I_	5.0	- μΑ	
at rated DC blocking voltage		T <sub>A</sub> = 125 °C	- I <sub>R</sub>	150		
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	25		
Typical reverse recovery time	1F - 0 7, VR - 00 V,	T <sub>J</sub> = 25 °C	- t <sub>rr</sub>	40	ns	
		T <sub>J</sub> = 100 °C		55		
Typical stored charge	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$	T <sub>J</sub> = 25 °C	Qrr	25	nC	
	$dI/dt = 50 \text{ A/µs}, I_{rr} = 10 \% I_{RM}$ $T_{J} = 100 ^{\circ}\text{C}$		Vrr	60	110	
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Typical thermal registance	R <sub>0JA</sub> (1)	50			°C/W
Typical thermal resistance	R <sub>0</sub> JL (1)		15		C/VV

### Note

 $<sup>^{(1)}</sup>$  Units mounted on PCB with 12.0 mm x 12.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH3D-E3/57T	0.211	57T	850	7" diameter plastic tape and reel		
ESH3D-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		
ESH3DHE3_A/H (1)	0.211	Н	850	7" diameter plastic tape and reel		
ESH3DHE3_A/I (1)	0.211	I	3500	13" diameter plastic tape and reel		

#### Note

<sup>(1)</sup> AEC-Q101 qualified

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

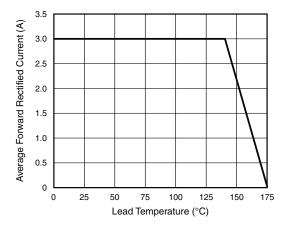


Fig. 1 - Maximum Forward Current Derating Curve

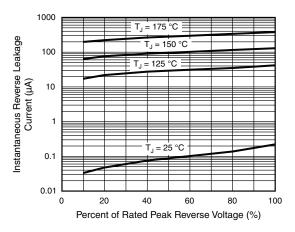


Fig. 4 - Typical Reverse Leakage Characteristics

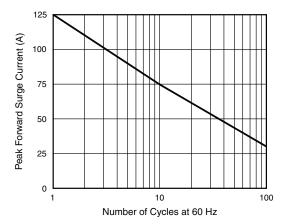


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

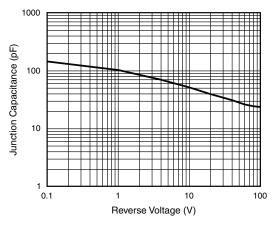


Fig. 5 - Typical Junction Capacitance

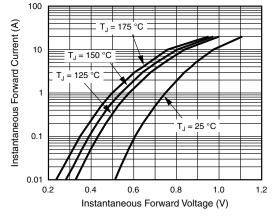


Fig. 3 - Typical Instantaneous Forward Characteristics

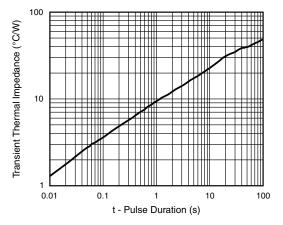


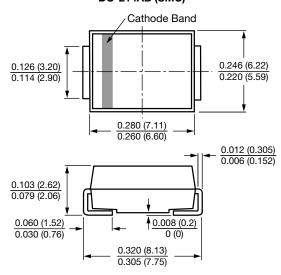
Fig. 6 - Typical Transient Thermal Impedance



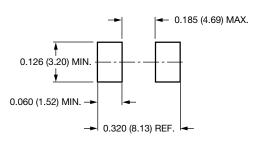
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### DO-214AB (SMC)



### **Mounting Pad Layout**





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